

## GN8062

## GaAs IC

For semiconductor laser drive

## ■ Features

- High-speed switching
- High output
- Pulse current and DC bias current can be controlled.

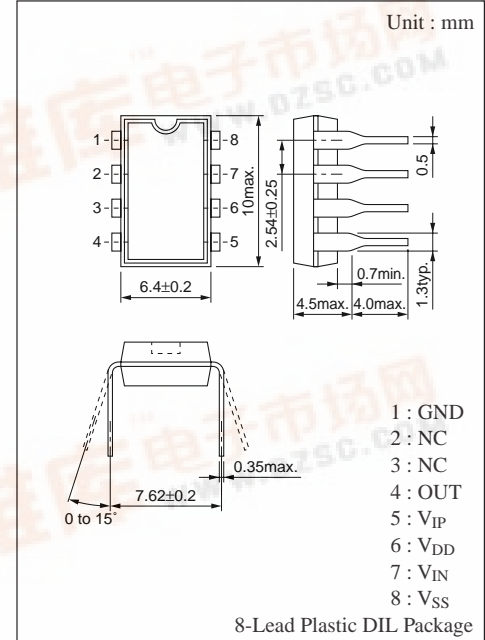
## ■ Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Rating	Unit
Power supply voltage	V <sub>DD</sub>	6	V
	V <sub>SS</sub>	-6	V
Pin voltage	V <sub>IN</sub>	-0.5 to V <sub>DD</sub> -1.5	V
	V <sub>IP</sub> <sup>*5</sup>	1.5 to V <sub>DD</sub>	V
	V <sub>OUT</sub> <sup>*1</sup>	V <sub>DD</sub>	V
Power current	I <sub>DD</sub> <sup>*4</sup>	50	mA
	I <sub>SS</sub>	40	mA
Output current	I <sub>OUT</sub>	145	mA
Allowable power dissipation	P <sub>D</sub> <sup>*2</sup>	700	mW
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C
Operating ambient temperature	T <sub>opr</sub> <sup>*3</sup>	-10 to +75	°C

- \*1 Do not apply the voltage higher than the set V<sub>DD</sub>.  
 \*2 Guaranteed value of the unit at Ta=25°C.  
 \*3 Range in which the IC circuit function operates and not the guaranteed range of electric characteristics.  
 \*4 I<sub>DD</sub> is a current when the pulse output current is zero.  
 \*5 Voltage when the constant current source has been connected.

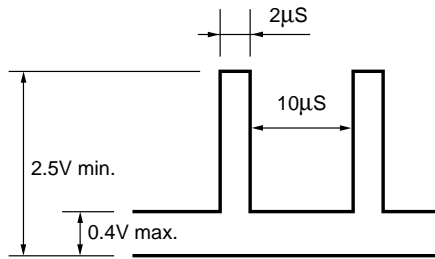
## ■ Electrical Characteristics (Ta = 25°C)

Parameter	Symbol	Test circuit	Condition	Min	Typ	Max	Unit
Pulse output current	I <sub>pmax</sub>	1	V <sub>DD</sub> =5V, V <sub>SS</sub> =-5V, V <sub>IN</sub> =2V, I <sub>p</sub> =120mA, R <sub>L</sub> =10Ω	100	120		mA
	I <sub>pmin</sub>	1	V <sub>DD</sub> =5V, V <sub>SS</sub> =-5V, V <sub>IN</sub> =0.4V, I <sub>p</sub> =120mA, R <sub>L</sub> =10Ω		1	5	mA
Supply current	I <sub>DD</sub> <sup>*1</sup>	2	V <sub>DD</sub> =5V, V <sub>SS</sub> =-5V, V <sub>IN</sub> =0.4V		35	50	mA
	I <sub>SS</sub>	2	I <sub>p</sub> =0, R <sub>L</sub> =10Ω		25	40	mA
Input voltage	V <sub>IH</sub>			2.5			V
	V <sub>IL</sub>					0.4	V
Rise time	t <sub>r</sub> <sup>*2</sup>	3	V <sub>DD</sub> =5V, V <sub>SS</sub> =-5V, I <sub>p</sub> =100mA			7	ns
Fall time	t <sub>f</sub> <sup>*2</sup>	3	R <sub>L</sub> =10Ω			5	ns



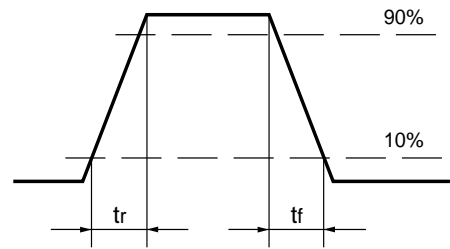
- \* 1 The current value to be supplied from the 5V power supply is a total sum of this value plus the pulse output current and bias output current.
- \* 2 Waveform of input and output signals

Input signal



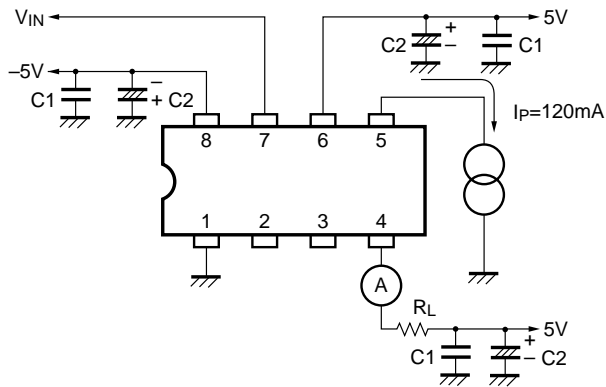
\* The rise/fall time of the input signal is 2ns (10 to 90%)

Output waveform

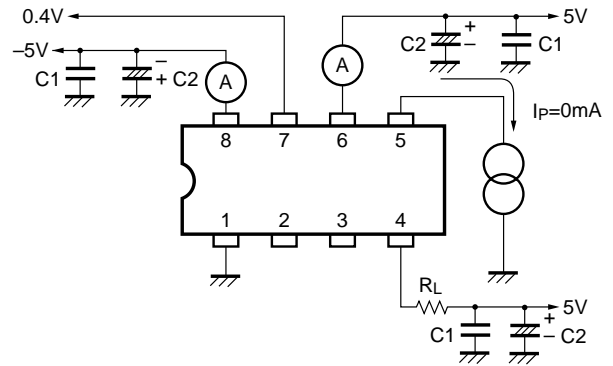


$t_r$  ... 10% to 90%  
 $t_f$  ... 90% to 10%

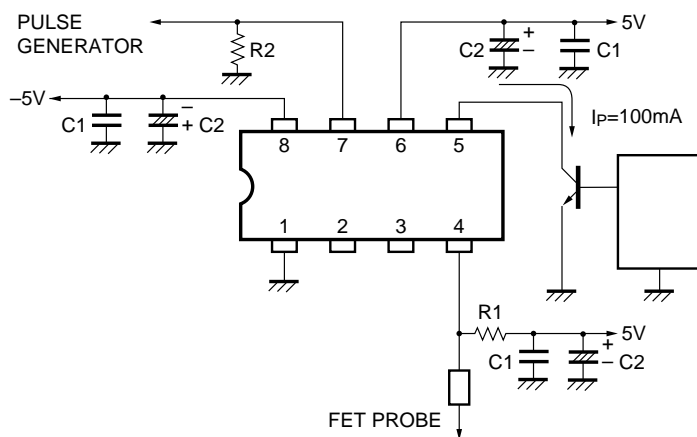
Test circuit 1



Test circuit 2

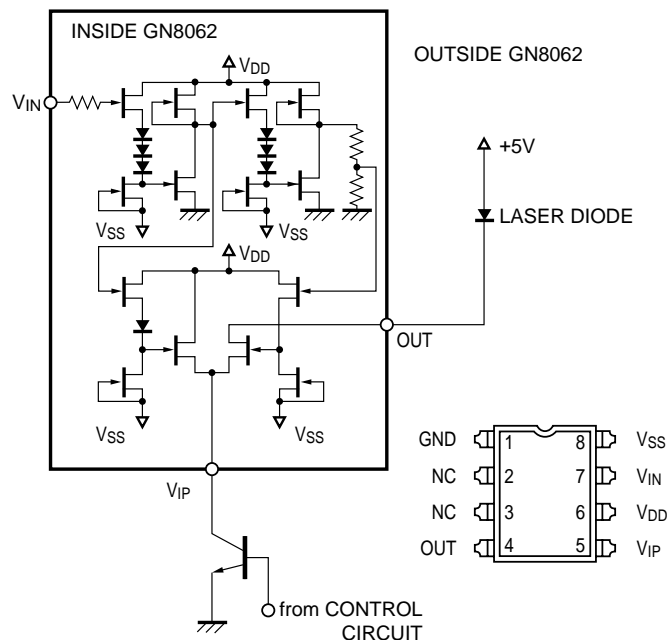


Test circuit 3



$C_1$  :  $0.1\mu\text{F}$   
 $C_2$  :  $3.3\mu\text{F}$   
 $R_1$  :  $10\Omega$   
 $R_2$  :  $50\Omega$

## ■ Block Diagram



## ■ Caution for Handling

- 1) The recommended  $V_{IN}$  voltage is 2.5 to 3V for [H] and 0 to 0.4V for [L].
- 2) Do not apply  $V_{IN}$  while the power supply is OFF.
- 3) For the current source to be connected to the  $V_{IP}$  pin, use a Si bipolar transistor as shown in the circuit diagram.

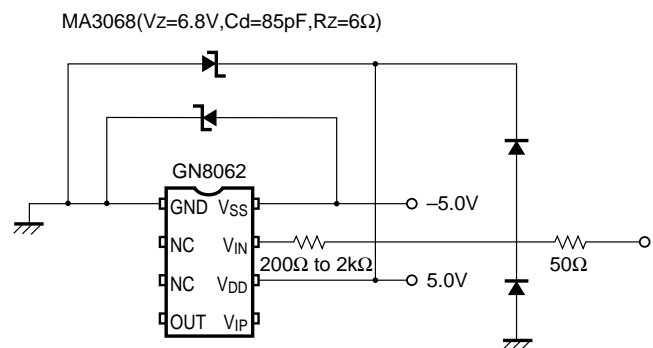
(Example: 2SD874)

To connect a resistor to the emitter or collector, use a resistor of a few ohm. The use of higher resistor may cause large change in the voltage at the  $V_{IP}$  pin, and may make the output waveform distortion. (See the pulse output current control example).

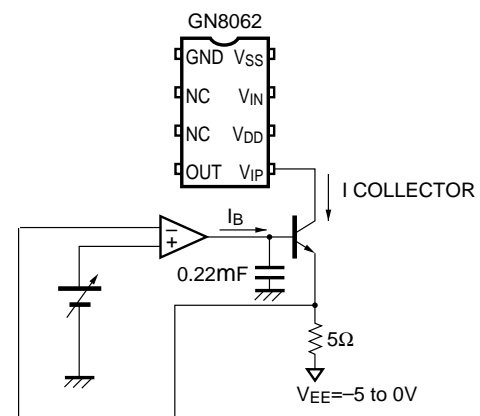
To use another current control circuit, set so that the  $V_{IP}$  pin voltage becomes around 2V.

- 4) When mounting, minimize the connection distance between the semiconductor laser and IC, and use the chip parts (C, R) of less parasitic effects.
- 5) Attention to damage by the power surge (see the example connection of the pin protection circuit).  
During handling, take care to ground the human body and solder iron tip.
- 6) When the power supply is turned ON and OFF, set the current value of the current source connected to the  $V_{IP}$  pin to zero. This is important to prevent the large current flow through the semiconductor laser during power ON/OFF.

When the power supply is ON, be sure to turn ON  $V_{DD}$ , after  $V_{SS}$  is completely equal to  $-5V$ . When the power supply is OFF, be sure to turn OFF  $V_{SS}$ , after  $V_{DD}$  is completely 0V.



Connection example of pin protection circuit



Example of pulse output current control circuit